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A	PPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
	09/552,383	04/19/2000	Stephen L. Willis	MICRON.092CP1	3147
	20995	7590 03/25/2004	EXAMINER		
	KNOBBE M 2040 MAIN S	ARTENS OLSON &	DIAZ, JOSE R		
	FOURTEENT		ART UNIT	PAPER NUMBER	
٠	IRVINE, CA	92614		2815	

DATE MAILED: 03/25/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

		Applicatio	n No.	Applicant(s)				
Office Action Summary		09/552,38	3	WILLIS, STEPHEN	۱ L.			
		Examiner		Art Unit				
		José R Día	ız	2815				
Period fo	The MAILING DATE of this communication ap or Reply	ppears on the	cover sheet with the o	correspondence add	dress			
A SH THE - Exte after - If the - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR REP MAILING DATE OF THIS COMMUNICATION nsions of time may be available under the provisions of 37 CFR 1 SIX (6) MONTHS from the mailing date of this communication. period for reply specified above is less than thirty (30) days, a report of the provision of the maximum statutory period for reply within the set or extended period for reply will, by stature to reply within the set or extended period for reply will, by staturely received by the Office later than three months after the mailed patent term adjustment. See 37 CFR 1.704(b).	1.136(a). In no eve ply within the statu d will apply and wil tte, cause the appli	nt, however, may a reply be tir tory minimum of thirty (30) day I expire SIX (6) MONTHS from cation to become ABANDONE	nely filed rs will be considered timely the mailing date of this co D (35 U.S.C. § 133).	mmunication.			
Status								
1)⊠	Responsive to communication(s) filed on 26	February 200	14 .					
2a)□								
3)□								
Disposit	ion of Claims							
5)□ 6)⊠ 7)□	Claim(s) 30-37 and 56-62 is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration. Claim(s) is/are allowed. Claim(s) 30-37 and 56-62 is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction and/or election requirement.							
Applicat	ion Papers							
9)	The specification is objected to by the Examin	ner.						
10)	10) ☐ The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.							
	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
11)	Replacement drawing sheet(s) including the correction of the oath or declaration is objected to by the							
·	under 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some color None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.								
2) Notion Notion Notion Notion	nt(s) ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/0 er No(s)/Mail Date	98)	4) Interview Summary Paper No(s)/Mail D 5) Notice of Informal 6) Other:	ate	D-152)			

DETAILED ACTION

Continued Examination Under 37 CFR 1.114

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on February 26, 2004 has been entered.

Terminal Disclaimer

The terminal disclaimer filed on February 26, 2004 disclaiming the terminal portion of any patent granted on this application which would extend beyond the expiration date of US Pat. No. 6,576,553 B2 has been reviewed and is accepted. The terminal disclaimer has been recorded.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 30-37 and 56-62 are rejected under 35 U.S.C. 103(a) as being unpatentable over Andricacos et al. (US 6,268,291 B1) in view of Sandhu et al. (US Pat. No. 5,069,002).

Claims 30-32, 34 and 56-58, Andricacos et al. teaches a method comprising the steps of: forming a dielectric layer (the layer formed between stop layers 92 in figs. 4A and 5A, similar to the layer 54 in figure 2) of a first thickness on a semiconductor wafer (52) (see Fig. 2); forming an aperture in the dielectric layer (see opening) (see figs. 4A and 5A); positioning a shield layer (92) (see figs. 4A and 5A) of a material different than the dielectric layer (see col. 8, lines 31-34 and 37-38, col. 9, lines 50-54; and col. 10, lines 17-18); positioning a sacrificial layer (94) (see figs. 4A and 5A); depositing conductive material (90 and 100) (see figs. 4A and 5A); removing the conductive material and the sacrificial layer using a CMP process (see figs. 4B and 5B and col. 10, lines 21-22 and 30-31) adapted to remove the conductive material (90 and 100) and the sacrificial layer (94) until the shield layer (92) is reached (see figs. 4B and 5B), wherein the shield layer (92) is more resistant to planarization by the CMP process than the sacrificial layer (94) (please note that the shield layer 92, contrary to the sacrificial layer 94, remains after the planarization step, see figs. 4B and 5B), and wherein the shield layer (92) inhibits thinning of the dielectric layer (the layer between the stop layers 92) during the CMP process (please note that the planarization is stopped when the shield layer 92 is exposed, see figs. 4B and 5B), and wherein interposing the sacrificial layer (94) between the conductive material (90 and 100) and the shield layer (92) reduces the amount of conductive material on the shield layer following the CMP process (see figs.

4B and 5B). Furthermore, Andricacos et al. teaches halting the CMP process when the sacrificial layer (94) has been removed (see figs. 4B and 5B) so as to maintain the dielectric layer (the layer between the stop layers 92) at the first thickness (please note that the shield layer 92 protects the dielectric layers from the effect of the planarization step, see figs. 4B and 5B).

However, Andricacos et al. is silence with respect to the limitation of detecting when the CMP process has removed the sacrificial layer. Sandhu et al. teach that is well known in the art to perform a sensing step during the CMP process, in which the change in friction is detected by rotating the wafer and polishing surfaces with electric motors and measuring current changes on one or both of the motors (see abstract and col. 3, lines 38-41 and 55-63 and col. 4, lines 28-30).

Andricacos et al. and Sandhu et al. are analogous art because they are from the same field of endeavor as applicant's invention. At the time of the invention it would have been obvious to a person of ordinary skill in the art to include the step of detecting when the CMP process has removed the sacrificial layer. The motivation for doing so, as is taught by Sandhu et al., is providing a control means for adjusting or stopping the process (abstract). Therefore, it would have been obvious to combine Sandhu et al. with Andricacos et al. to obtain the invention of claims 30-37 and 56-62.

Regarding claims 33, 36, 59 and 61, Andricacos et al. teaches that it is very well known in the art to select an oxide material for the dielectric and/or the sacrificial layers, and a nitride material for the shield layer (see col. 8, lines 31-34, 37-38 and 51-53, col. 9, lines 50-54; and col. 10, lines 17-18), and hence, the use of the claimed particular

materials (i.e. BPSG and oxynitride (DARC)) to make the dielectric, shield and sacrificial layers, absent any criticality, are only considered to be the use of "optimum" or "preferred" materials that a person having ordinary skill in the art at the time the invention was made using routine experimentation would have found obvious to provide for the dielectric, shield and sacrificial layers in the device disclosed by Andricacos et al. since they are well known types of materials used to make such layers and since it has been held to be a matter of obvious design choice and within the general skill of a worker in the art to select a known material on the basis of its suitability for the intended use of the invention. In re Leshin, 125 USPQ 416.

Regarding claims 35 and 60, Andricacos et al. teaches that the shield layer (92) is comprised of silicon nitride (see col. 10, lines 17-18 and 26-27).

Regarding claims 37 and 62, Denning et al. teaches a cavity (consider the damascene structure) filled with the conductive material (90 or 100) (see figs. 4B and 5B).

Response to Arguments

Applicant's arguments with respect to claims 30-37 and 56-62 have been considered but are moot in view of the new ground of rejection.

Correspondence

Any inquiry concerning this communication or earlier communications from the examiner should be directed to José R Díaz whose telephone number is (571) 272-1727. The examiner can normally be reached on 9:00-5:00 Monday through Friday.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Tom Thomas can be reached on (571) 272-1664. The fax phone number

for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the

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JRD 3/18/04 Tom Norms
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